

University of California at Berkeley
College of Engineering
Dept. of Electrical Engineering and Computer Sciences

EE 105 Midterm 2

Spring 2006

Prof. Ming C. Wu

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Guidelines

- Closed book and notes.
- Two pages of information sheets allowed.
- Total time = 90 minutes

- (1) For the circuit shown in Fig. 1, $W/L = 2$ for both M_1 and M_2 , $\mu_n C_{ox} = 100 \mu\text{A}/\text{V}^2$, $\lambda = 0.05 \text{ V}^{-1}$, $V_{Tn} = 1\text{V}$, $V_{DD} = 5\text{V}$.
- [5 pt] Find the DC drain current at M_2 when $V_{OUT} = 3\text{V}$. Use $\lambda = 0$ for this part.
 - [5 pt] Find the DC gate bias (V_G) of M_2 such that the DC output voltage $V_{OUT} = 3\text{V}$. Use $\lambda = 0$ for this part.
 - [5 pt] Draw the small-signal equivalent circuit. Find the values of all circuit elements in the small signal circuit (e.g., g_m , r_0 , ...).
 - [5 pt] Find the voltage gain, $A_V = v_{out} / v_s$.
 - [5 pt] Find the output resistance of the circuit (both expression and numeric value).
 - [5 pt] Find the input resistance, and construct the two-port model of this voltage amplifier.

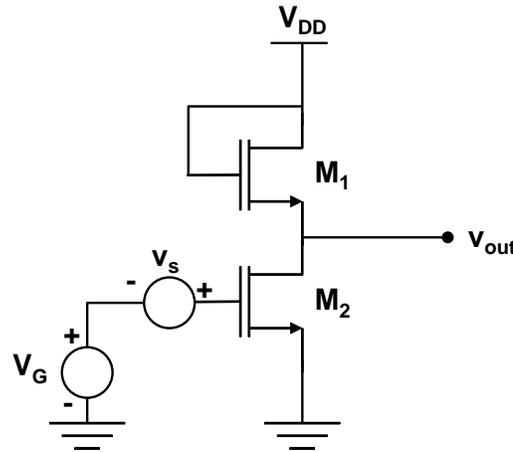


Fig. 1

- (2) Consider the following circuit with $(W/L)_1 = 2$, $(W/L)_2 = 1$, $\mu_p C_{ox} = 50 \mu\text{A}/\text{V}^2$, $\mu_n C_{ox} = 100 \mu\text{A}/\text{V}^2$, $\lambda_n = \lambda_p = 0.05 \text{ V}^{-1}$, $V_{Tn} = 1\text{V}$ and $V_{Tp} = -1\text{V}$, $V_{DD} = 5\text{V}$:
- [10 pt] The gate is biased at 2.5V DC. Show that both transistors are in saturation regime. Find the expression and numeric value of small-signal voltage gain, $A_V = v_{out} / v_s$.
 - [10 pt] Find the maximum and the minimum voltage at the output of this circuit when both transistors stay in saturation regime.

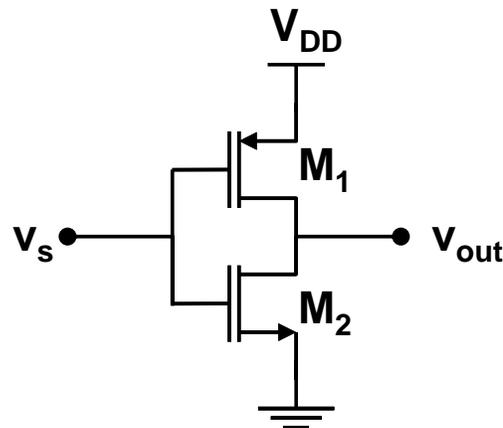


Fig. 2

- (3) Consider the following circuit with 3 PMOS transistors: $(W/L)_1 = 10$, $(W/L)_2 = 20$, $(W/L)_3 = 100$, $\mu_p C_{ox} = 50 \mu\text{A}/\text{V}^2$, $\lambda = 0.05 \text{ V}^{-1}$, $V_{Tp} = -1 \text{ V}$, $I_{REF} = 10 \mu\text{A}$, $V_+ = 3 \text{ V}$, $V_- = -3 \text{ V}$, $R_L = 100 \text{ K}\Omega$.
- [5 pt] Can you identify any functional block in this circuit (i.e., any portion of the circuit that performs a known function)? Replace that functional block, and draw a simplified circuit of the amplifier.
 - [10 pt] Find the expression of the voltage gain, $A_v = v_{out} / v_s$, and then find its numerical value.
 - [10 pt] Find both the expression and the numeric value of the output resistance of the amplifier.

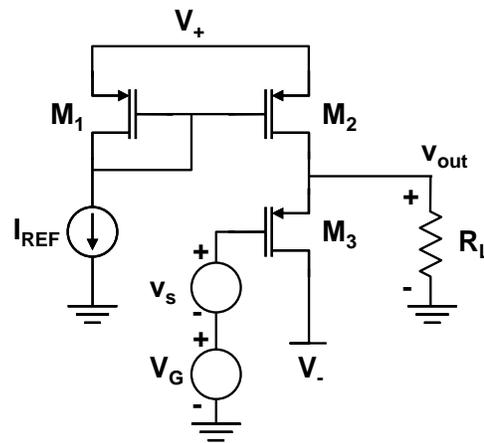


Fig. 3

- (4) The frequency response of an amplifier is shown in the figure below.

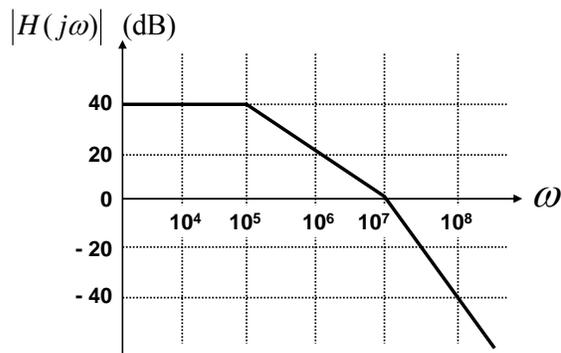


Fig. 4A

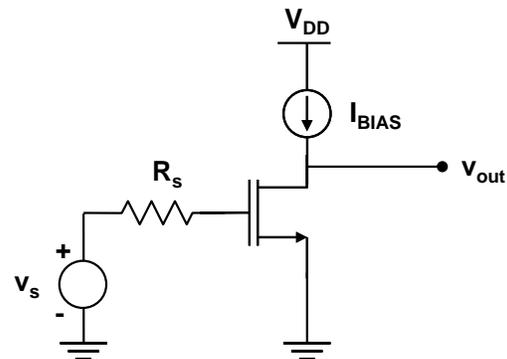


Fig. 4B

- [8 pt] Find the transfer function of the frequency response shown in Fig. 4A.
- [7 pt] This transfer function can be realized by the circuit in Fig. 4B. Draw the small-signal circuit that includes C_{gd} . For simplicity, we will neglect C_{gs} . Analysis of this circuit can be simplified by Miller approximation. Draw the simplified small-signal equivalent circuit. Show the Miller capacitances explicitly in terms of other circuit parameters.
- [10 pt] The following parameters of the circuit are given:
 $I_{BIAS} = 10 \mu\text{A}$, $\lambda = 0.1 \text{ V}^{-1}$, $r_{oc} = \infty$ (ideal current source).
 If the frequency response of the amplifier matches the transfer function shown in Fig. 4A, find the numeric values of the transistor parameters: C_{gd} , r_0 , g_m , and the circuit parameter, R_s .

Some equations

Threshold voltage (NMOS)

$$V_{Tn} = V_{FB} - 2\phi_p + \frac{1}{C_{ox}} \sqrt{2q\epsilon_s N_a (-2\phi_p)}$$

$$V_{Tn} = V_{Tn0} + \gamma \left(\sqrt{V_{SB} - 2\phi_p} - \sqrt{-2\phi_p} \right)$$

$$\phi_p = -\frac{kT}{q} \ln \frac{N_a}{n_i}$$

NMOS equations:

$$I_D = 0, \quad V_{GS} < V_{Tn}$$

$$i_D = \frac{W}{L} \mu C_{ox} \left(V_{GS} - V_{Tn} - \frac{V_{DS}}{2} \right) V_{DS} (1 + \lambda V_{DS}), \quad V_{GS} > V_{Tn}, V_{DS} < V_{GS} - V_{Tn}$$

$$i_D = \frac{W}{L} \frac{\mu C_{ox}}{2} (V_{GS} - V_{Tn})^2 (1 + \lambda V_{DS}), \quad V_{GS} > V_{Tn}, V_{DS} > V_{GS} - V_{Tn}$$

MOS capacitances in saturation $C_{GS} = (2/3)WLC_{ox} + C_{ov}$ $C_{ov} = L_D W C_{ox}$

MOS signal parameters:

$$g_m = \left. \frac{\partial i_D}{\partial V_{GS}} \right|_{V_{GS}, V_{DS}} = \mu C_{ox} \frac{W}{L} (V_{GS} - V_{Tn}) (1 + \lambda V_{DS})$$

$$\approx \mu C_{ox} \frac{W}{L} (V_{GS} - V_{Tn})$$

$$= \sqrt{2i_D \left(\frac{W}{L} \right) \mu C_{ox}}$$

$$r_o = \left(\left. \frac{\partial i_D}{\partial V_{DS}} \right|_{V_{GS}, V_{DS}} \right)^{-1} \approx \frac{1}{\lambda I_{DS}}$$

$$g_{mb} = \left. \frac{\partial i_D}{\partial V_{BS}} \right|_Q = \frac{\gamma g_m}{2\sqrt{-V_{BS} - 2\phi_p}}$$

(1) (a) current determined by M_1

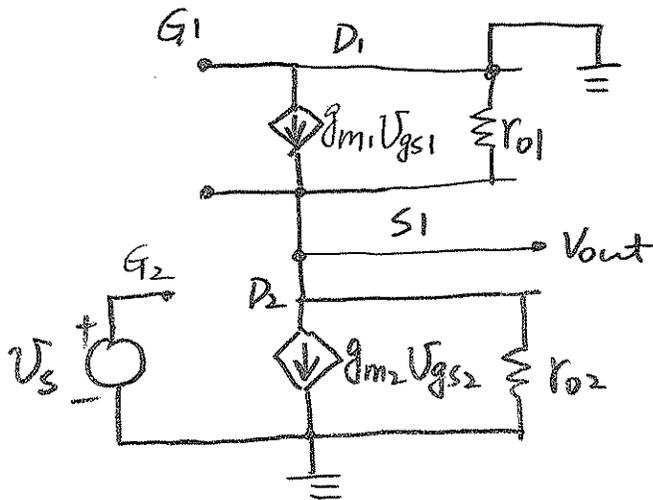
$$V_{GS1} = V_{DS1} = V_{DD} - V_{out} = 5 - 3 = 2V \quad \text{When } V_{out} = 3V$$

$$I_{D2} = I_{D1} = \left(\frac{W}{L}\right) \cdot \frac{\mu_n C_{ox}}{2} (V_{GS1} - V_{Tn})^2 = 2 \cdot \frac{100}{2} \cdot 1^2 = 100 \mu A$$

(b) $I_{D2} = I_{D1} = \left(\frac{W}{L}\right) \cdot \frac{\mu_n C_{ox}}{2} (V_{GS2} - V_{Tn})^2 = 100$

$$V_{GS2} - V_{Tn} = 1 \Rightarrow V_{GS2} = 2V$$

(c)



$$g_{m1} = \mu_n C_{ox} \left(\frac{W}{L}\right) (V_{GS1} - V_{Tn})$$

$$= 100 \cdot 2 \cdot 1 = 200 \mu S$$

$$g_{m2} = \mu_n C_{ox} \left(\frac{W}{L}\right) (V_{GS2} - V_{Tn})$$

$$= 200 \mu S$$

$$r_{o1} = \frac{1}{\lambda I_{D1}} = \frac{1}{0.05 \cdot 100 \cdot 10^{-6}} = 200 k\Omega$$

$$r_{o2} = \frac{1}{\lambda I_{D2}} = 200 k\Omega$$

$$V_{GS1} = 0 - V_{out} = -V_{out}$$

$$V_{GS2} = V_S$$

(d) KCL at D_2 :

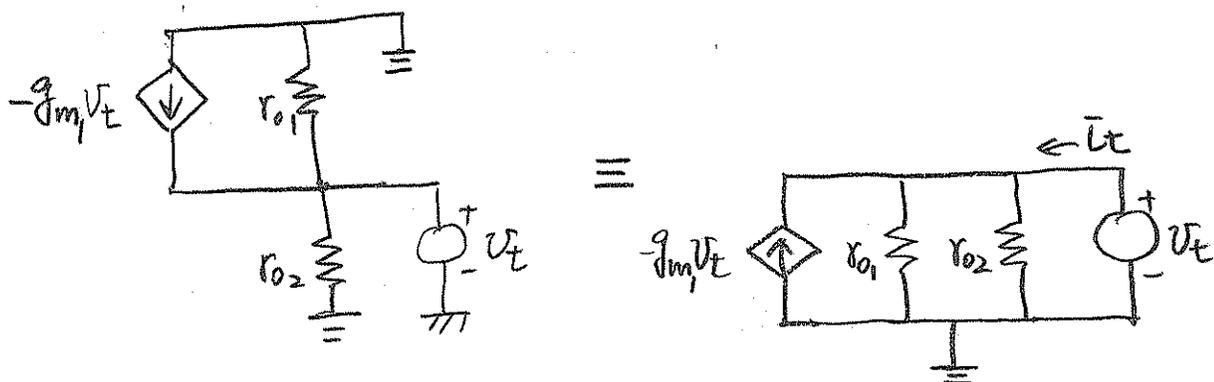
$$g_{m2} V_S + \frac{V_{out}}{r_{o2}} - g_{m1} (-V_{out}) + \frac{V_{out}}{r_{o1}} = 0$$

$$r_{o1} = r_{o2} = r_o$$

$$A_v = \frac{V_{out}}{V_S} = \frac{-g_{m2}}{g_{m1} + \frac{2}{r_o}} = -\frac{2 \times 10^{-4}}{2 \times 10^{-4} + \frac{2}{2 \times 10^5}} = -\frac{2}{2.1} = -0.95$$

(e) Set $V_S = 0$, $V_{out} \rightarrow V_E$

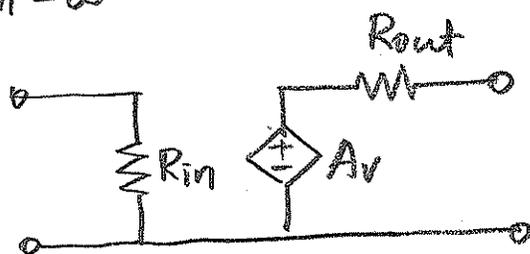
$$\Rightarrow V_{GS2} = 0$$



$$\bar{i}_t = \frac{v_t}{r_{o1}} + \frac{v_t}{r_{o2}} - (-g_{m1}v_t)$$

$$\Rightarrow R_{out} = \frac{v_t}{\bar{i}_t} = [g_{m1} + \frac{2}{r_o}]^{-1} = [2.1 \times 10^{-4}]^{-1} = 4.76 \text{ k}\Omega$$

(f) $R_{in} = \infty$



$R_{in} = \infty$

$$R_{out} = [g_{m1} + \frac{2}{r_o}]^{-1} = 4.76 \text{ k}\Omega$$

$$A_v = - \frac{g_{m2}}{[g_{m1} + \frac{2}{r_o}]} = -0.95$$

(2) (a) $V_{SG1} = V_{DD} - V_S = 2.5 \text{ V}$, $V_{GS2} = V_S - 0 = 2.5 \text{ V}$

$$-I_{DP1} = \left(\frac{W}{L}\right)_1 \cdot \frac{\mu_p C_{ox}}{2} \cdot (V_{SG1} - |V_{TP}|)^2 \cdot (1 + \lambda_p V_{SD1})$$

$$I_{D2} = \left(\frac{W}{L}\right)_2 \cdot \frac{\mu_n C_{ox}}{2} \cdot (V_{GS2} - V_{TN})^2 \cdot (1 + \lambda_n V_{DS2})$$

$$V_{SD1} = V_{DD} - V_{out} = 5 - V_{out}$$

$$V_{DS2} = V_{out} - 0 = V_{out}$$

$$\lambda_n = \lambda_p = \lambda$$

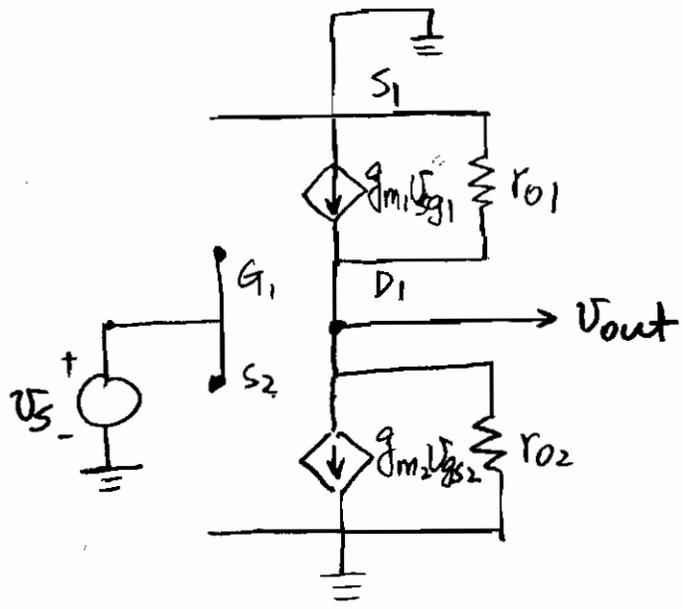
$$-I_{DP1} = I_{D2} \text{ , since } \left(\frac{W}{L}\right)_1 \cdot \frac{\mu_p C_{ox}}{2} = \left(\frac{W}{L}\right)_2 \cdot \left(\frac{\mu_n C_{ox}}{2}\right)$$

$$\Rightarrow 1 + \lambda(5 - V_{out}) = 1 + \lambda \cdot V_{out}$$

$$\Rightarrow V_{out} = 2.5 \text{ V}$$

For M_1 , $V_{SG1} - |V_{TP}| = 2.5 - 1 = 1.5 \text{ V} < V_{SD1} = 2.5 \Rightarrow M_1$ in Saturation

For M_2 , $V_{GS2} - V_{TN} = 2.5 - 1 = 1.5 \text{ V} < V_{DS2} = 2.5 \Rightarrow M_2$ in Saturation



$$V_{sg1} = 0 - V_S = -V_S$$

$$V_{gs2} = V_S - 0 = V_S$$

$$g_{m1} = \left(\frac{W}{L}\right)_1 \mu_p C_{ox} (V_{sg1} - |V_{TP}|)$$

$$= 2.50 \cdot (2.5 - 1) = 150 \mu S$$

$$g_{m2} = \left(\frac{W}{L}\right)_2 \mu_n C_{ox} (V_{gs2} - V_{TN})$$

$$= 1 \cdot 100 (2.5 - 1) = 150 \mu S$$

$$-I_{DP1} = I_{D2} \approx \left(\frac{W}{L}\right)_2 \frac{\mu_n C_{ox}}{2} \cdot (V_{gs2} - V_{TN})^2$$

$$= 50 \cdot 1.5^2 = 112.5 \mu A$$

$$R_{O1} = R_{O2} = \frac{1}{\lambda I_D} = 178 \text{ k}\Omega$$

KCL at $D_1 = D_2$

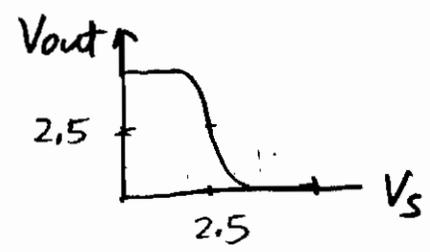
$$g_{m2} \cdot V_S + \frac{V_{out}}{R_{O2}} - g_{m1} \cdot (-V_S) + \frac{V_{out}}{R_{O1}} = 0$$

$$A_V = \frac{V_{out}}{V_S} = - \frac{g_{m1} + g_{m2}}{\frac{1}{R_{O1} \parallel R_{O2}}} = - \frac{1}{2} (g_{m1} + g_{m2}) \cdot R_O = 26.7$$

(b) Maximum Voltage occurs when M_1 is on the verge of saturation:

$$V_{SD1} = V_{DD} - V_{out} = V_{sg1} - |V_{TP}|$$

$$= V_{DD} - V_S - |V_{TP}|$$



$$\Rightarrow V_S = V_{out} - |V_{TP}|$$

$$I_1 = \left(\frac{W}{L}\right)_1 \frac{\mu_p C_{ox}}{2} [V_{DD} - V_{out}]^2 = I_2 = \left(\frac{W}{L}\right)_2 \frac{\mu_n C_{ox}}{2} [(V_{out} - |V_{TP}|) - V_{TN}]^2$$

$$\Rightarrow V_{DD} - V_{out} = V_{out} - |V_{TP}| - V_{TN} \Rightarrow V_{out} = \frac{1}{2} (V_{DD} + |V_{TP}| + V_{TN}) = \underline{3.5} \#$$

Minimum Vout: M_2 at verge of sat. $\Rightarrow V_S = V_{out} + V_{TN}$

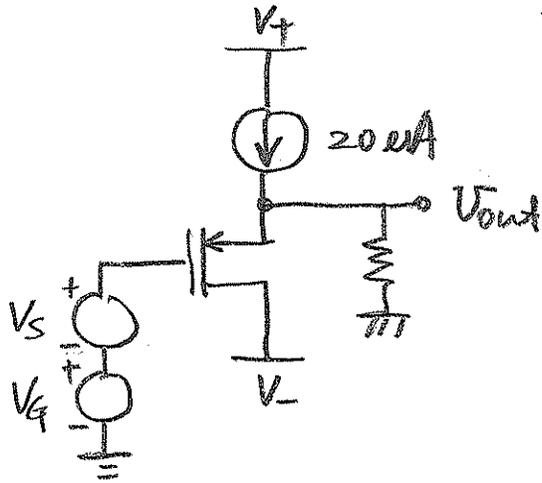
$$I_1 = I_2 \Rightarrow V_{DD} - (V_{out} + V_{TN}) - |V_{TP}| = V_{out}$$

$$\Rightarrow V_{out} = \frac{1}{2} (V_{DD} - |V_{TP}| - V_{TN}) = \underline{1.5} \#$$

(3) (a) M_1 and M_2 form current mirror

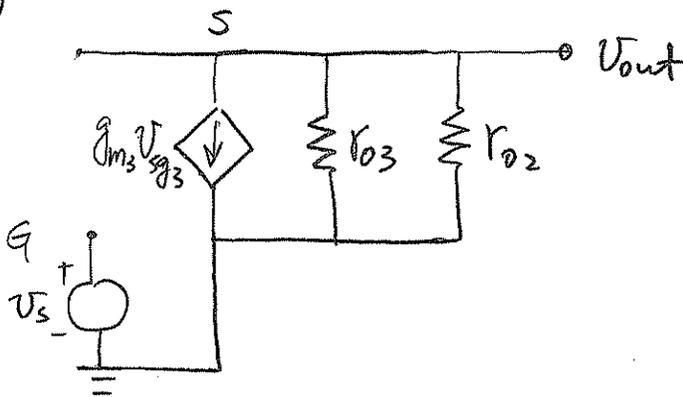
4.

$$I_{D2} = I_{REF} \cdot \left(\frac{W}{L}\right)_2 / \left(\frac{W}{L}\right)_1 = 2 I_{REF} = 20 \mu A$$



The resistance looking into $M_2 = r_{o2}$

(b)



$$V_{sg3} = (V_{out} - V_s)$$

$$\text{KCL at } s: g_{m3}(V_{out} - V_s) + \frac{V_{out}}{r_{o3} // r_{o2}} = 0$$

$$\Rightarrow A_v = \frac{V_{out}}{V_s} = \frac{g_{m3}}{g_{m3} + \frac{1}{r_{o3} // r_{o2}}}$$

Use DC analysis to find g_{m3} , r_{o2} , r_{o3}

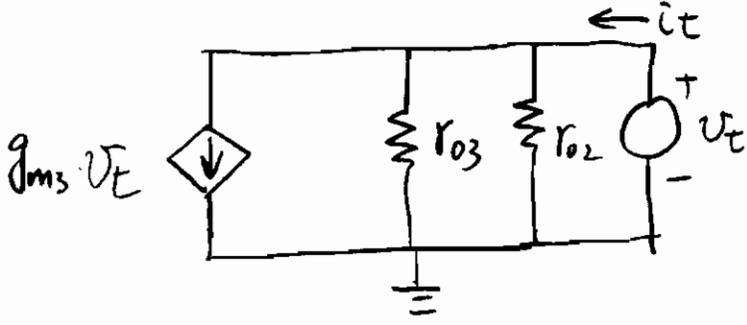
$$I_{D3} = 20 \mu A = \left(\frac{W}{L}\right)_3 \cdot \frac{\mu_p C_{ox}}{2} \cdot (V_{SG} - |V_{TP}|)^2 = 100 \cdot \frac{50}{2} (V_{SG} - |V_{TP}|)^2 \mu A$$

$$V_{SG} - |V_{TP}| = \sqrt{\frac{40}{5000}} = 0.089$$

$$g_{m3} = \left(\frac{W}{L}\right)_3 \cdot \mu_p C_{ox} (V_{GS} - |V_{TP}|) = \frac{2 I_{D3}}{(V_{SG} - |V_{TP}|)} = 449 \mu S$$

$$r_{o3} = \frac{1}{\lambda I_{D3}} = \frac{1}{0.05 \cdot 20 \times 10^{-6}} = 1 M\Omega \quad r_{o2} = \frac{1}{\lambda I_{D2}} = 1 M\Omega$$

(c) set $V_S = 0$, $V_{sg3} = V_{out} - 0 = V_{out} \rightarrow V_E$

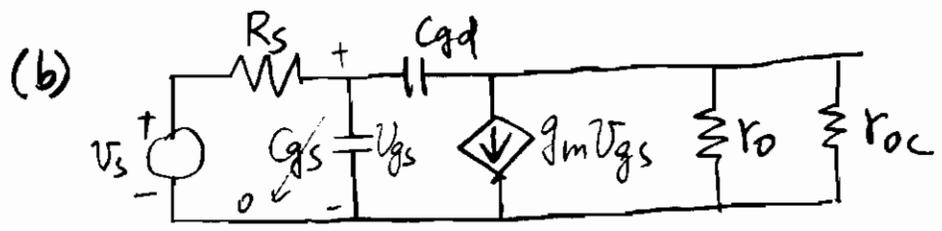


$$\bar{i}_t = \frac{V_E}{r_{o2} // r_{o3}} + g_m V_E$$

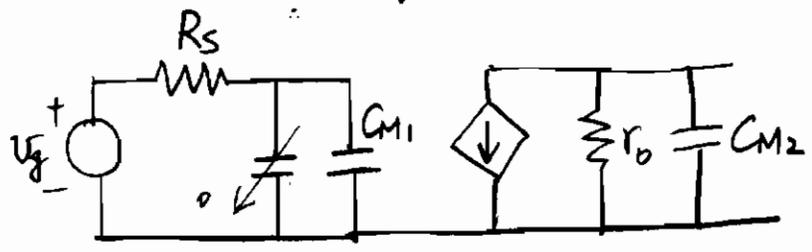
$$\Rightarrow R_{out} = \frac{V_E}{\bar{i}_t} = \frac{1}{g_m3 + \frac{1}{r_{o2} // r_{o3}}} = 2.2 \text{ k}\Omega$$

(4) (a) $\omega_{p1} = 10^5$, $\omega_{p2} = 10^7$

$$H(j\omega) = \frac{100}{(1 + j\frac{\omega}{10^5})(1 + j\frac{\omega}{10^7})}$$



↓ Miller Approximation



$$C_{M1} = (1 + g_m r_o) \cdot C_{gd}$$

$$C_{M2} = (1 + \frac{1}{g_m r_o}) \cdot C_{gd}$$

$$(c) r_o = \frac{1}{\lambda I_{BIAS}} = \frac{1}{0.01 \times 10 \times 10^{-6}} = 1 \text{ M}\Omega$$

$$\tau_1 = R_s C_{M1} = R_s \cdot (1 + g_m r_o) \cdot C_{gd}$$

$$\tau_2 \hat{=} r_o \cdot C_{gd}$$

$$C_{gd} = \frac{\tau_2}{r_o} = \frac{\omega_{p2}^{-1}}{r_o} = \frac{10^{-7}}{10^6} = 10^{-13}$$

$$g_m r_o = 40 \text{ dB} = 10^2 = 100$$

$$g_m = \frac{100}{10^6} = 10^{-4} = 100 \mu\text{S}$$

$$\tau_1 = 10^{-5} \approx R_s \cdot (101) \cdot 10^{-13} \approx R_s \cdot 10^{-11}$$

$$\Rightarrow R_s = 10^6 = 1 \text{ M}\Omega.$$